

ST93003

High voltage fast-switching PNP power transistor

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Application

■ Electronic ballast for fluorescent lighting

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA. The ST93003 is expressly designed for a new solution to be used in compact fluorescent lamps, where it is coupled with the ST83003, its complementary NPN transistor.

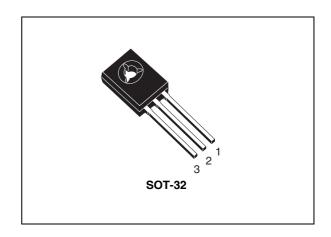


Figure 1. Internal schematic diagram

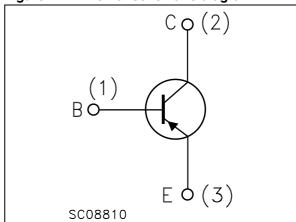


Table 1. Device summary

Order code	Marking Package		Packaging	
ST93003	93003	SOT-32	Tube	

Contents ST93003

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ST93003 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	-500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-400	
V _{EBO}	Emitter-base voltage $(I_C = 0, I_B = -0.75 \text{ A}, t_p < 10 \mu\text{s})$	V _{(BR)EBO}	V
I _C	Collector current	-1.5	Α
I _{CM}	Collector peak current (t _p < 5 ms)	-3	Α
I _B	Base current	-0.75	Α
I _{BM}	Base peak current ($t_p < 5 \text{ ms}$)	-1.5	Α
P _{TOT}	Total dissipation at T _c = 25 °C	40	W
T _{stg}	Storage temperature	-65 to 150	°C
T _j	Max. operating junction temperature	150	°C

Electrical characteristics ST93003

2 Electrical characteristics

(T_{case}= 25 °C unless otherwise specified)

Table 3. On/off states

Symbol	Parameter	Took conditions	Value			Unit
Symbol		Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = -500 V V _{CE} = -500 V, T _C = 125 °C			-1 -5	mA mA
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C =0)	I _E = -10 mA	-5		-10	V
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B =0)	I _C = -10 mA	-400			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = -0.5 \text{ A}, I_B = -0.1 \text{ A}$ $I_C = -0.35 \text{ A}, I_B = -50 \text{ mA}$			-0.5 -0.5	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = -0.5 A, I _B = -0.1 A			-1	V
h _{FE} ⁽¹⁾	DC current gain	I_{C} = -10 mA, V_{CE} = -5 V I_{C} = -0.35 A, V_{CE} = -5 V I_{C} = -1 A, V_{CE} = -5 V	10 16 4	25	32	
t _r t _s	Resistive load Rise time Storage time Fall time	I_{C} = -0.35 A, V_{CC} = 125 V, I_{B1} = -70 mA, I_{B2} = 70 mA $I_{p} \ge$ 25 μ s (see Figure 14)	1.5	90 2.2 0.1	2.9	ns µs µs
t _s	Inductive load Storage time Fall time	I_{C} = -0.5 A, I_{B1} = -0.1 A, $V_{BE(off)}$ = 5 V, L = 10 mH, V_{clamp} = 300 V (see Figure 13)		400 40		ns ns
E _{sb}	Avalanche energy	L = 4 mH, C = 1.8 nF, I _{BR} = 2.5 A, 25 °C < T _C < 125 °C	12			mJ

^{1.} Pulsed: pulse duration = 300 μs, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating

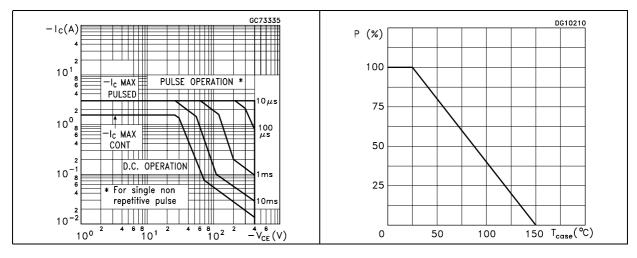


Figure 4. DC current gain

Figure 5. DC current gain

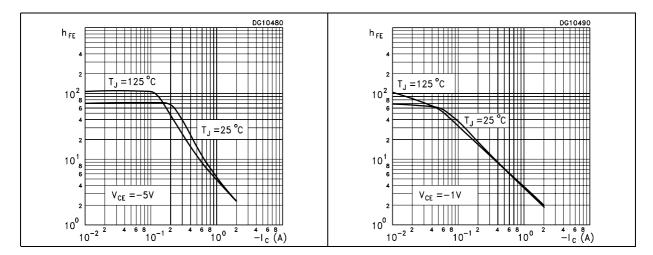
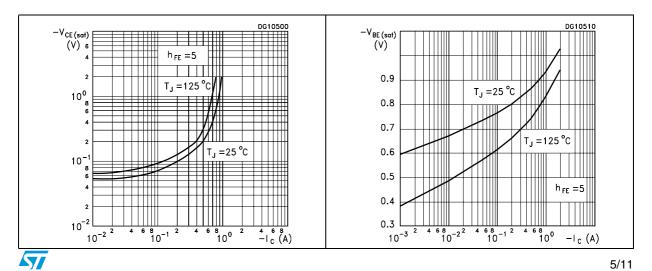


Figure 6. Collector emitter saturation voltage Figure 7. Base emitter saturation voltage



Electrical characteristics ST93003

Figure 8. Resistive load fall time

Figure 9. Resistive load storage time

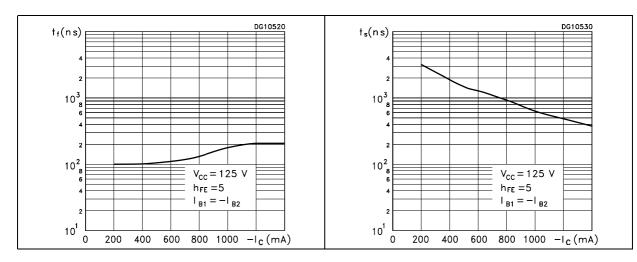


Figure 10. Inductive load fall time

Figure 11. Inductive load storage time

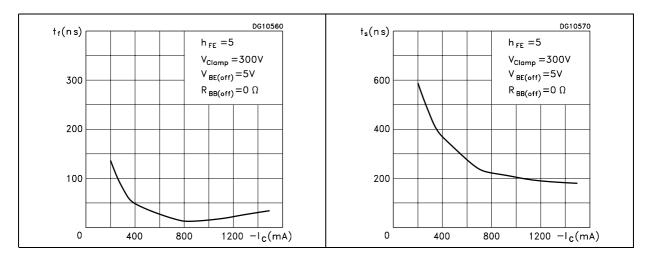
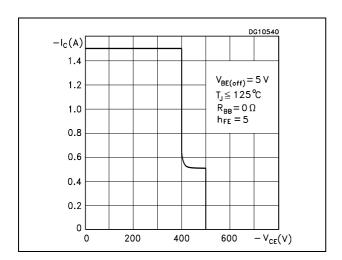


Figure 12. Reverse biased SOA



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ST93003 Test circuits

3 Test circuits

Figure 13. Inductive load switching

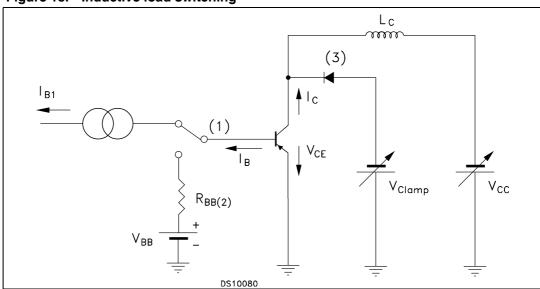
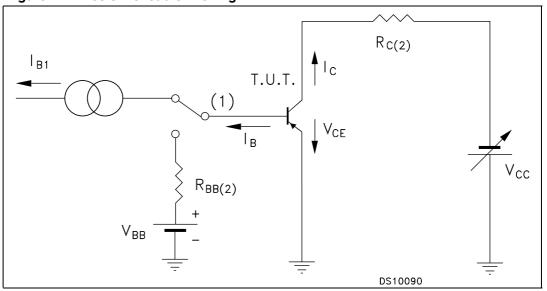


Figure 14. Resistive load switching



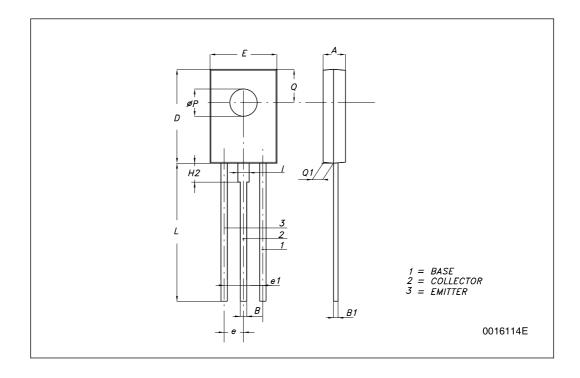
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4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

SOT-32 (TO-126) MECHANICAL DATA

DIM	mm.			
DIM.	MIN.	TYP	MAX.	
Α	2.4		2.9	
В	0.64		0.88	
B1	0.39		0.63	
D	10.5		11.05	
E	7.4		7.8	
е	2.04	2.29	2.54	
e1	4.07	4.58	5.08	
L	15.3		16	
Р	2.9		3.2	
Q		3.8		
Q1	1		1.52	
H2		2.15		
I		1.27		



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Revision history ST93003

5 Revision history

Table 4. Document revision history

Date	Revision	Changes
21-Jun-2004	2	
08-Jul-2008	3	- Mechanical data has been updated - The document has been reformatted

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